TOSHIBA Integrated IGBT Module Silicon N Channel IGBT

MIG150J202H

High Power Switching Applications Motor Control Applications

• Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.

• The electrodes are isolated from case.

• High speed type IGBT: VCE (sat) = 2.8V (max)

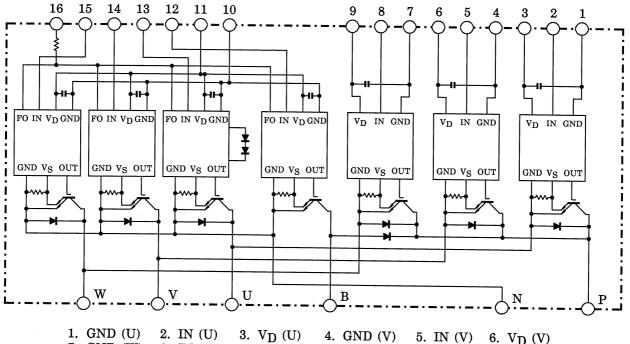
 $t_{off} = 3.0 \ \mu s \ (max)$

 $t_{rr} = 0.30 \ \mu s \ (max)$

• Package dimensions : TOSHIBA 2-110A1A

• Weight: 520g

Equivalent Circuit



1 2001-05-29

Maximum Ratings ($T_j = 25$ °C)

Stage	Characteristic	Condition	SymboL	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V _{CC}	450	V
	Collector-emitter voltage	_	V _{CES}	600	V
	Collector current	Tc = 25°C, DC	IC	150	Α
	Forward current	Tc = 25°C, DC	IF	150	Α
	Collector power dissipation	Tc = 25°C	PC	320	W
	Junction temperature	_	Tj	150	°C
	Supply voltage	P-N power terminal	V _{CC}	450	V
Brake	Collector-emitter voltage	_	V _{CES}	600	V
	Collector current	Tc = 25°C, DC	IC	50	Α
	Reverse voltage	_	V _R	600	V
	Forward current	Tc = 25°C, DC	l _F	50	Α
	Collector power dissipation	Tc = 25°C	PC	120	W
	Junction temperature	_	Tj	150	°C
	Control supply voltage	V _D -GND terminal	V _D	20	V
Control	Input voltage	IN-GND terminal	V _{IN}	20	V
Control	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	14	mA
	Operating temperature	_	TC	-20 ~ 100	°C
Module	Storage temperature range	_	T _{stg}	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M5		3	N·m

Electrical Characteristics ($T_j = 25$ °C)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	I _{CEX}	V _{CE} = 600 V	T _j = 25°C	_	_	1	mA
Collector cut-on current			T _j = 125°C	_	_	20	IIIA
Collector-emitter saturation voltage	V _{CE (sat)}	$V_D = 15 \text{ V}, I_C = 150 \text{ A}$ $V_{IN} = 15 \text{ V} \rightarrow 0 \text{ V}$	T _j = 25°C	ı	2.2	2.8	V
Collector-entitler saturation voltage			T _j = 125°C	_	2.3	_	
Forward voltage	V _F	I _F = 150 A		_	2.5	3.5	٧
	t _{on}	V _{CC} =300 V, I _C = 150 A V _D = 15 V, V _{IN} = 15 V ↔ 0 V		_	1.2	2.0	- µs
Switching time	t _{off}			ı	2.0	3.0	
Ownering time	t _f	Inductive load	(Note 1)	_	0.25	0.5	μδ
	t _{rr}	(Note 1		_	0.1	0.3	



b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	ICEX	V _{CE} = 600V	T _j = 25°C	_	_	1	mA
Collector cut-on current			T _j = 125°C	_	_	20	IIIA
Collector-emitter saturation voltage	V _{CE (sat)}	$V_D = 15V, I_C = 50A$ $V_{IN} = 15V \rightarrow 0V$	T _j = 25°C	_	2.0	3.0	· V
			T _j = 125°C	_	2.0	_	
Reverse current	IR	V _R = 600V	T _j = 25°C	_	_	1	- mA
Reverse current			T _j = 125°C	_	_	20	
Forward voltage	V _F	I _F = 50A		_	2.2	2.5	V
	t _{on}	V _{CC} = 300V, I _C = 50A V _D = 15V, V _{IN} = 15V ↔ 0V		_	1.0	2.0	
Switching time	t _{off}			_	2.0	3.0	
Switching time	t _f	Inductive load	(NIata 4)	_	0.25	0.5	μs
	t _{rr}		(Note 1)	_	0.15	0.3	

c. Control Stage $(T_j = 25^{\circ}C)$

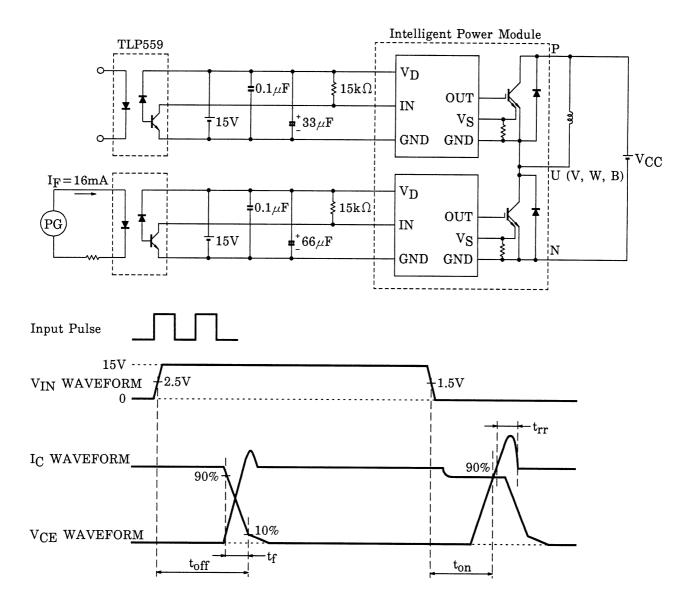
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I _{D (H)}	- V _D = 15 V	_	8	_	mA
	Low side	I _{D (L)}		_	32	_	IIIA
Input-on signal vo	oltage	V _{IN (on)}	V _D = 15 V, I _C = 150 mA	1.3	1.5	1.7	V
Input-off signal voltage		V _{IN (off)}	V _D = 15 V, I _C = 150 mA	2.2	2.5	2.8	V
Fault output current	Protection	I _{FO (on)}	- V _D = 15 V	8	10	12	mA
	Normal	I _{FO (off)}		_	_	1	
Over current protection trip level	Inverter	OC	V _D = 15 V, T _j = 125°C	190	300	_	A
	Brake			60	_	_	
Short current protection trip level	Inverter	00	V - 45 V T - 405°C	285	450	_	^
	Brake	SC	$V_D = 15 \text{ V}, T_j = 125^{\circ}\text{C}$	90	_	_	Α
Over current cut-off time		t _{off (OC)}	V _D = 15 V	_	5	_	μs
Over temperature protection	Trip level	ОТ	Case temperature	110	118	125	- °C
	Reset level	OTr		_	98	_	
Control supply under voltage protection	Trip level	UV		11.0	12.0	12.5	.,
	Reset level	UVr	_	_	12.5	_	V
Fault output pulse width		t _{FO}	V _D = 15 V	1	2	3	ms



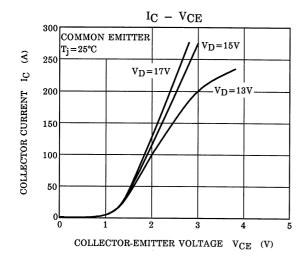
d. Thermal Resistance ($T_j = 25$ °C)

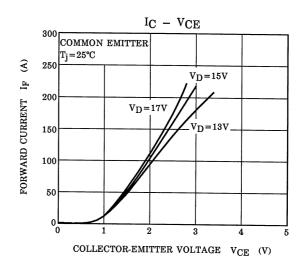
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
		Inverter IGBT	_	_	0.390	· °C/W
Junction to case thermal resistance	D., a .	Inverter FRD	_	_	1.041	
Junction to case thermal resistance		Brake IGBT	_	_	1.041	
		Brake FRD	_	_	2.000	
Case to fin thermal resistance	R _{th (c-f)}	Compound is applied	_	0.05	_	°C/W

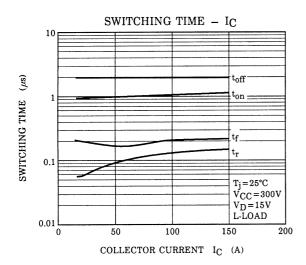
Note 1: Switching time test circuit & timing chart

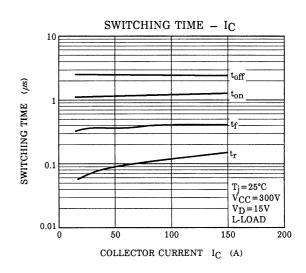


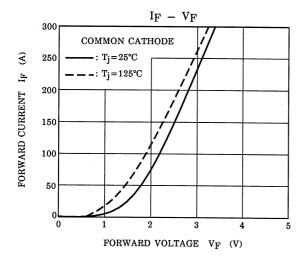
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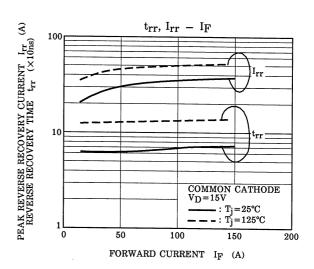


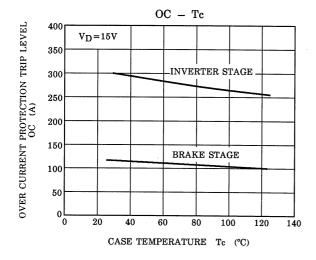


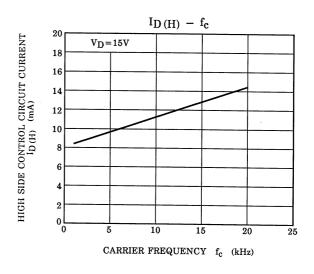


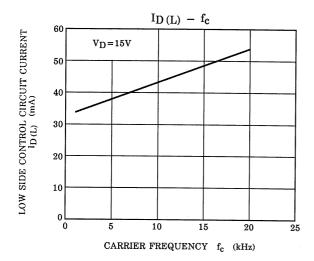


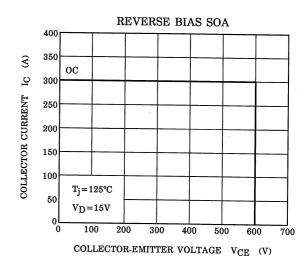


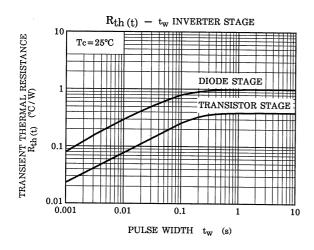


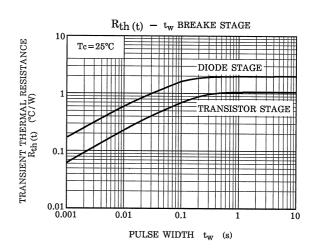






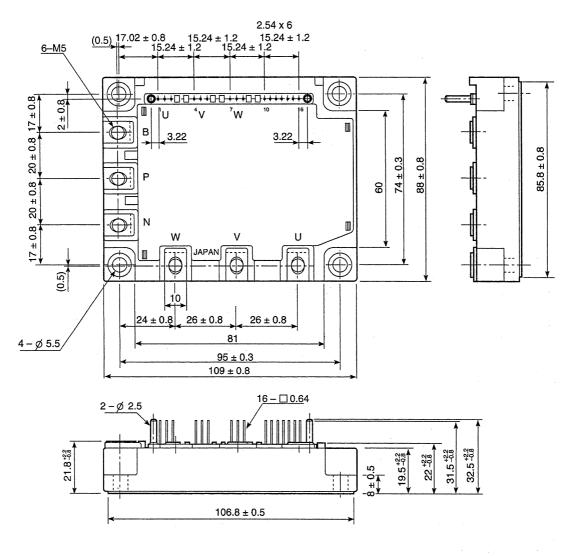






Package Dimensions: TOSHIBA 2-110A1A

Unit: mm



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